Low-power configurable gate with voltage-level translatorRev. 5 — 15 August 2012Product data sheet

### 1. General description

The 74AUP1T58 provides low-power, low-voltage configurable logic gate functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XOR, inverter and buffer. All inputs can be connected to  $V_{CC}$  or GND.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 2.3 V to 3.6 V.

The 74AUP1T58 is designed for logic-level translation applications with input switching levels that accept 1.8 V low-voltage CMOS signals, while operating from either a single 2.5 V or 3.3 V supply voltage.

The wide supply voltage range ensures normal operation as battery voltage drops from 3.6 V to 2.3 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Schmitt trigger inputs make the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range.

### 2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 1.5 \ \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

# nexperia

### Low-power configurable gate with voltage-level translator

## 3. Ordering information

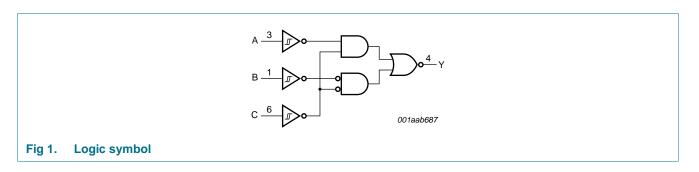
Table 1. Ordering	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP1T58GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1T58GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1.45 $\times$ 0.5 mm	SOT886
74AUP1T58GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 $\times$ 1 $\times$ 0.5 mm	SOT891
74AUP1T58GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115
74AUP1T58GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202

### 4. Marking

Table 2. Marking	
Type number	Marking code <sup>[1]</sup>
74AUP1T58GW	a8
74AUP1T58GM	a8
74AUP1T58GF	a8
74AUP1T58GN	a8
74AUP1T58GS	a8

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

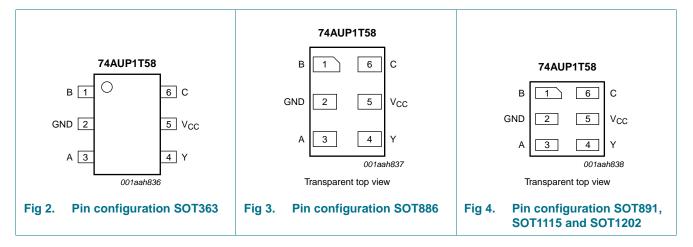
### 5. Functional diagram



Low-power configurable gate with voltage-level translator

## 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Y	4	data output
V <sub>CC</sub>	5	supply voltage
С	6	data input

## 7. Functional description

Table 4.	Function table <sup>[1]</sup>		
Input		Output	
С	В	Α	Y
L	L	L	L
L	L	Н	Н
L	Н	L	L
L	Н	Н	Н
Н	L	L	Н
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	L

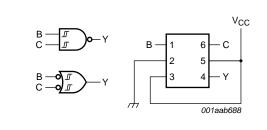
[1] H = HIGH voltage level; L = LOW voltage level.

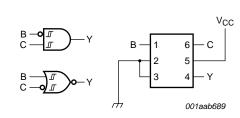
Low-power configurable gate with voltage-level translator

### 7.1 Logic configurations

#### Table 5.Function selection table

Logic function	Figure
2-input NAND	see Figure 5
2-input NAND with both inputs inverted	see Figure 8
2-input AND with inverted input	see <u>Figure 6</u> and <u>7</u>
2-input NOR with inverted input	see <u>Figure 6</u> and <u>7</u>
2-input OR	see Figure 8
2-input OR with both inputs inverted	see Figure 5
2-input XOR	see Figure 9
Buffer	see Figure 10
Inverter	see Figure 11





## Fig 5. 2-input NAND gate or 2-input OR gate with both inputs inverted

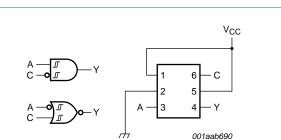


Fig 7. 2-input AND gate with input C inverted or 2-input NOR gate with inverted A input



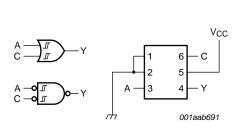
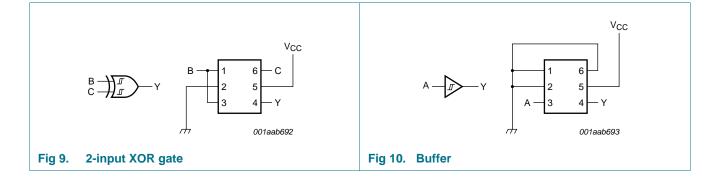
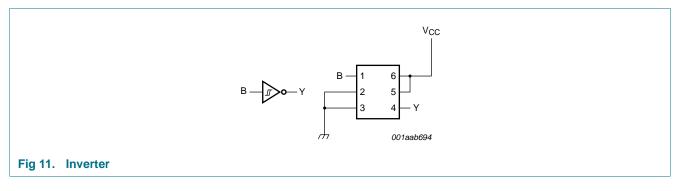


Fig 8. 2-input OR gate or 2-input NAND gate with both inputs inverted



#### Low-power configurable gate with voltage-level translator



#### **Limiting values** 8.

#### Table 6. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>1</sub> < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
I <sub>O</sub>	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	٥C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SC-88 package: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K. [2] For XSON6 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

#### **Recommended operating conditions** 9.

Table 7.	Recommended operating cond	ditions			
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C

### 4141

74AUP1T58 **Product data sheet** 

### Low-power configurable gate with voltage-level translator

## **10. Static characteristics**

#### Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C					
V <sub>T+</sub>	positive-going threshold	$V_{CC}$ = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.75	-	1.16	V
V <sub>T-</sub>	negative-going threshold	$V_{CC}$ = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.50	-	0.85	V
V <sub>H</sub>	hysteresis voltage	$(V_H=V_{T+}-V_{T-})$				
		$V_{CC}$ = 2.3 V to 2.7 V	0.23	-	0.60	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.25	-	0.56	V
V <sub>ОН</sub>	HIGH-level output voltage	$V_I = V_{T+} \text{ or } V_{T-}$				
		$I_{O}$ = –20 $\mu A; V_{CC}$ = 2.3 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7$ mA; $V_{CC} = 3.0$ V	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		$I_0 = 20 \ \mu$ A; $V_{CC} = 2.3 \ V$ to 3.6 V	-	-	0.10	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
I <sub>I</sub>	input leakage current	$V_1$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.1	μA
$\Delta I_{OFF}$	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I <sub>CC</sub>	supply current	$V_{I} = \text{GND or } V_{\text{CC}}; I_{\text{O}} = 0 \text{ A};$ $V_{\text{CC}} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.2	μA
CI	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_{I}$ = GND or $V_{CC}$	-	0.8	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF
T <sub>amb</sub> = -	-40 °C to +85 °C					
V <sub>T+</sub>	positive-going threshold	$V_{CC}$ = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.75	-	1.19	V
V <sub>T-</sub>	negative-going threshold	$V_{CC}$ = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.50	-	0.85	V
V <sub>H</sub>	hysteresis voltage	$(V_H = V_T+ - V_T-)$				
		$V_{CC}$ = 2.3 V to 2.7 V	0.10	-	0.60	V

### Low-power configurable gate with voltage-level translator

#### Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>он</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = –20 $\mu A;$ V_{CC} = 2.3 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		$I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 2.3 V to 3.6 V	-	-	0.1	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
		$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.45	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
I	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
OFF	power-off leakage current	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.5	μA
∆l <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.5	μA
СС	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.5	μA
∆l <sub>CC</sub>	additional supply current	$V_{CC}$ = 2.3 V to 2.7 V; $I_{O}$ = 0 A	<u>[1]</u> -	-	4	μA
		$V_{CC}$ = 3.0 V to 3.6 V; I <sub>O</sub> = 0 A	[2] _	-	12	μA
Γ <sub>amb</sub> = −	40 °C to +125 °C					
V <sub>T+</sub>	positive-going threshold	$V_{CC}$ = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.75	-	1.19	V
V <sub>T-</sub>	negative-going threshold	$V_{CC}$ = 2.3 V to 2.7 V	0.33	-	0.64	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.46	-	0.85	V
V <sub>H</sub>	hysteresis voltage	$(V_H = V_T+ - V_T-)$				
		$V_{CC} = 2.3 \text{ V} \text{ to } 2.7 \text{ V}$	0.10	-	0.60	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.15	-	0.56	V
√ <sub>ОН</sub>	$ \begin{aligned} &  _{0} = -20 \ \mu^{2}, V_{CC} = 2.3 \ V \ 0.3 \ V \ V_{CC} - 0.1 \ & & - \\ &  _{0} = -2.3 \ m^{2}, V_{CC} = 2.3 \ V & 1.97 \ & & - \\ &  _{0} = -3.1 \ m^{2}, V_{CC} = 2.3 \ V & 1.85 \ & & - \\ &  _{0} = -3.1 \ m^{2}, V_{CC} = 3.0 \ V & 2.57 \ & & - \\ &  _{0} = -4.0 \ m^{2}, V_{CC} = 3.0 \ V & 2.55 \ & & - \\ &  _{0} = -20 \ \mu^{2}, V_{CC} = 2.3 \ V \ 0.50 \ V & - \ & & - \\ &  _{0} = -20 \ \mu^{2}, V_{CC} = 2.3 \ V \ 0.50 \ V & - \ & & - \\ &  _{0} = -20 \ m^{2}, V_{CC} = 2.3 \ V \ & - \ & - \ & 0.1 \ \\ &  _{0} = 2.3 \ m^{2}, V_{CC} = 2.3 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.7 \ m^{2}, V_{CC} = 3.0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.7 \ m^{2}, V_{CC} = 3.0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.7 \ m^{2}, V_{CC} = 3.0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.7 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & 0.45 \ \\ &  _{0} = 2.0 \ m^{2}, V_{CC} = 0 \ V \ & - \ & - \ & - \ & 0.55 \ \\ &  _{0} = 1.0 \ V_{CC} = 0 \ V \ & 0.2 \ V \ \\ &  _{0} = 0 \ A \ &  _{0} = - \ & - \ & 1.5 \ \\ &  _{0} = -0 \ A \ & V_{CC} = 2.3 \ V \ 0.3 \ A \ & V_{CC} = - \ & 1.5 \ \\ &  _{0} = -2.3 \ V \ 0.3 \ A \ & V_{CC} = 0 \ A \ &  _{1} - \ & - \ & 1.5 \ \\ &  _{0} = - \ & - \ & 1.5 \ \\ &  _{0} = -2.3 \ V \ & 0.3 \ V \ & 0.75 \ & - \ & 1.10 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ A \ & 0.75 \ & - \ & 1.10 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ & 0 \ & 0.75 \ & - \ & 1.10 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ & 0 \ & 0.15 \ & - \ & 0.60 \ \\ & v_{CC} = 3.0 \ V \ 0.3 \ & 0 \ & 0.15 \ & - \ & 0.60 \ \\ & v_{CC} = -2.0 \ & 0.10 \ & - \ & 0.60 \ \\ & v_{CC} = -2.0 \ & 0.10 \ & - \ & 0.60 \ \\ & v_{CC} = -2.0 \ & 0.50 \ & 0.50 \ \\ & v_{CC} = -2.0 \ & 0.50 \ & 0.50 \ \\ & v_{CC} = -2.0 \ & 0.50 \ & 0.50 \$					
		$I_{O}$ = -20 $\mu$ A; V <sub>CC</sub> = 2.3 V to 3.6 V	V <sub>CC</sub> - 0.11	-	0.33 0.45 0.33 0.45 ±0.5 ±0.5 ±0.5 1.5 4 12 1.10 1.19 0.64 0.85 0.60 0.56 - - - - - - 0.11 0.36 0.50 0.36 0.50	V
		$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-	-	V
			1.67	-	-	V
		$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.40	-	-	V
			2.30	-	-	V
√ <sub>OL</sub>	LOW-level output voltage	$V_{I} = V_{T+}$ or $V_{T-}$				
02			-	-	0.11	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
			-	-		V
			-	-		V
			-	-		V
	input leakage current	0 00		-		μA
	Transa and a contraint		•			•
4AUP1T58	ata sheet	All information provided in this document is subject to legal discla Rev. 5 — 15 August 2012	aimers.		© Nexperia B.V. 2017. A	Il rights reserv 7 of 2

#### Low-power configurable gate with voltage-level translator

At recom	mended operating conditions	s; voltages are referenced to GND (grou	und = 0 V).			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>OFF</sub>	power-off leakage current	$V_{I} \text{ or } V_{O}$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.75	μA
$\Delta I_{OFF}$	additional power-off leakage current	$V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μA
I <sub>CC</sub>	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	3.5	μA
$\Delta I_{CC}$	additional supply current	$V_{CC}$ = 2.3 V to 2.7 V; $I_{O}$ = 0 A	<u>[1]</u> -	-	7	μA
		$V_{CC}$ = 3.0 V to 3.6 V; $I_O$ = 0 A	[2] _	-	22	μA

#### Table 8. Static characteristics ... continued

[1] One input at 0.3 V or 1.1 V, other input at  $V_{CC} \mbox{ or GND}.$ 

[2] One input at 0.45 V or 1.2 V, other input at V<sub>CC</sub> or GND.

### **11. Dynamic characteristics**

#### Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Parameter	Conditions		25 °C			–40 °C to +125 °C			
			Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)		
$V_{CC} = 2.2$	3 V to 2.7 V; V <sub>I</sub> = 1.6	5 V to 1.95 V								
t <sub>pd</sub>	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C <sub>L</sub> = 5 pF	2.1	3.6	5.6	0.5	6.8	7.5	ns	
		C <sub>L</sub> = 10 pF	2.6	4.1	6.2	1.0	7.9	8.7	ns	
		C <sub>L</sub> = 15 pF	3.0	4.6	6.8	1.0	8.7	9.6	ns	
		C <sub>L</sub> = 30 pF	4.0	5.8	8.1	1.5	10.8	11.9	ns	
$V_{CC} = 2.5$	3 V to 2.7 V; V <sub>I</sub> = 2.3	3 V to 2.7 V								
t <sub>pd</sub>	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C <sub>L</sub> = 5 pF	1.7	3.4	5.5	0.5	6.0	6.6	ns	
		C <sub>L</sub> = 10 pF	2.2	4.0	6.2	1.0	7.1	7.9	ns	
		C <sub>L</sub> = 15 pF	2.6	4.5	6.8	1.0	7.9	8.7	ns	
		C <sub>L</sub> = 30 pF	3.5	5.6	8.1	1.5	10.0	11.0	ns	
$V_{\rm CC} = 2.2$	3 V to 2.7 V; V <sub>I</sub> = 3.0	) V to 3.6 V								
t <sub>pd</sub>	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C <sub>L</sub> = 5 pF	1.4	3.2	5.1	0.5	5.5	6.1	ns	
		C <sub>L</sub> = 10 pF	1.9	3.7	5.8	1.0	6.5	7.2	ns	
		C <sub>L</sub> = 15 pF	2.2	4.2	6.3	1.0	7.4	8.2	ns	
		C <sub>L</sub> = 30 pF	3.2	5.4	7.7	1.5	9.5	10.5	ns	
$V_{CC} = 3.$	0 V to 3.6 V; V <sub>I</sub> = 1.6	65 V to 1.95 V								
t <sub>pd</sub>	propagation delay	A, B, C to Y; see Figure 12	[2]							
		C <sub>L</sub> = 5 pF	2.0	2.9	4.0	0.5	8.0	8.8	ns	
		C <sub>L</sub> = 10 pF	2.4	3.5	4.7	1.0	8.5	9.4	ns	
		C <sub>L</sub> = 15 pF	2.8	3.9	5.3	1.0	9.1	10.1	ns	
		C <sub>L</sub> = 30 pF	3.6	5.1	6.7	1.5	9.8	10.8	ns	

#### Low-power configurable gate with voltage-level translator

Symbol	Parameter	Conditions		25 °C		-4	0 °C to +1	25 °C	Unit
				Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>CC</sub> = 3.	0 V to 3.6 V; V <sub>I</sub> = 2.3	3 V to 2.7 V							
t <sub>pd</sub>	propagation delay	A, B, C to Y; see Figure 12							
		C <sub>L</sub> = 5 pF	1.6	2.8	4.4	0.5	5.3	5.9	ns
		C <sub>L</sub> = 10 pF	2.1	3.4	5.1	1.0	6.1	6.8	ns
		C <sub>L</sub> = 15 pF	2.4	3.9	5.6	1.0	6.8	7.5	ns
		C <sub>L</sub> = 30 pF	3.4	5.0	7.0	1.5	8.5	9.4	ns
V <sub>CC</sub> = 3.	0 V to 3.6 V; V <sub>I</sub> = 3.0	) V to 3.6 V							
t <sub>pd</sub>	propagation delay	A, B, C to Y; see Figure 12							
		C <sub>L</sub> = 5 pF	1.3	2.8	4.4	0.5	4.7	5.2	ns
		C <sub>L</sub> = 10 pF	1.7	3.3	5.1	1.0	5.7	6.3	ns
		C <sub>L</sub> = 15 pF	2.1	3.8	5.7	1.0	6.2	6.9	ns
		C <sub>L</sub> = 30 pF	3.1	4.9	7.0	1.5	7.8	8.6	ns
T <sub>amb</sub> = 2	5 °C								
C <sub>PD</sub>	power dissipation	$f_i = 1 \text{ MHz}; V_i = \text{GND to } V_{\text{CC}}$ [3]							
	capacitance	$V_{CC}$ = 2.3 V to 2.7 V	-	3.6	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	4.3	-	-	-	-	pF

#### Table 9. Dynamic characteristics ... continued

[1] All typical values are measured at nominal  $V_{\mbox{CC}}.$ 

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o}) \text{ where:}$ 

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

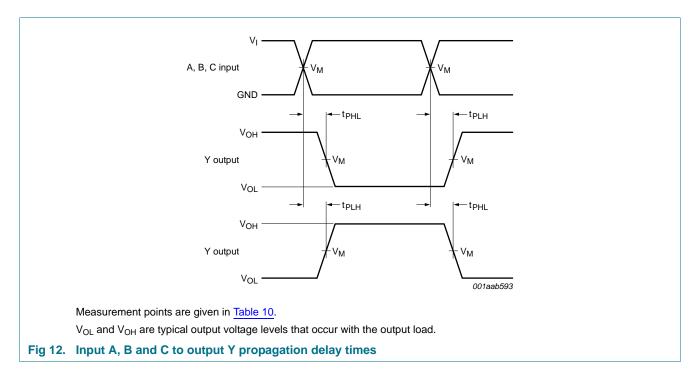
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

#### Low-power configurable gate with voltage-level translator

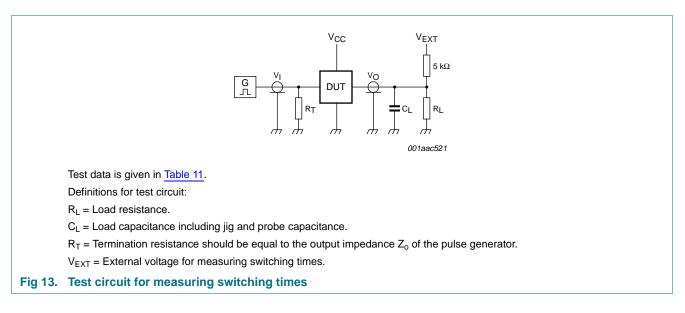
## 12. Waveforms



#### Table 10. Measurement points

Supply voltage	Output	Input		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	t <sub>r</sub> = t <sub>f</sub>
2.3 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_I$	1.65 V to 3.6 V	≤ 3.0 ns

#### Low-power configurable gate with voltage-level translator



#### Table 11. Test data

Supply voltage	Load		tage Load V <sub>EXT</sub>		
V <sub>cc</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k $\Omega$ or 1 M $\Omega$	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times  $R_L = 5 k\Omega$ , for measuring propagation delays, setup and hold times and pulse width  $R_L = 1 M\Omega$ .

Low-power configurable gate with voltage-level translator

## 13. Package outline

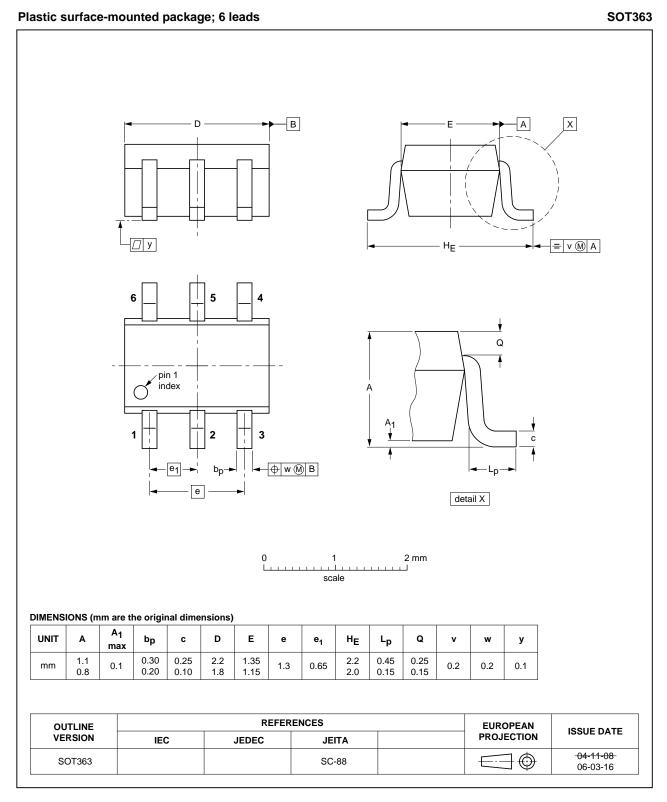
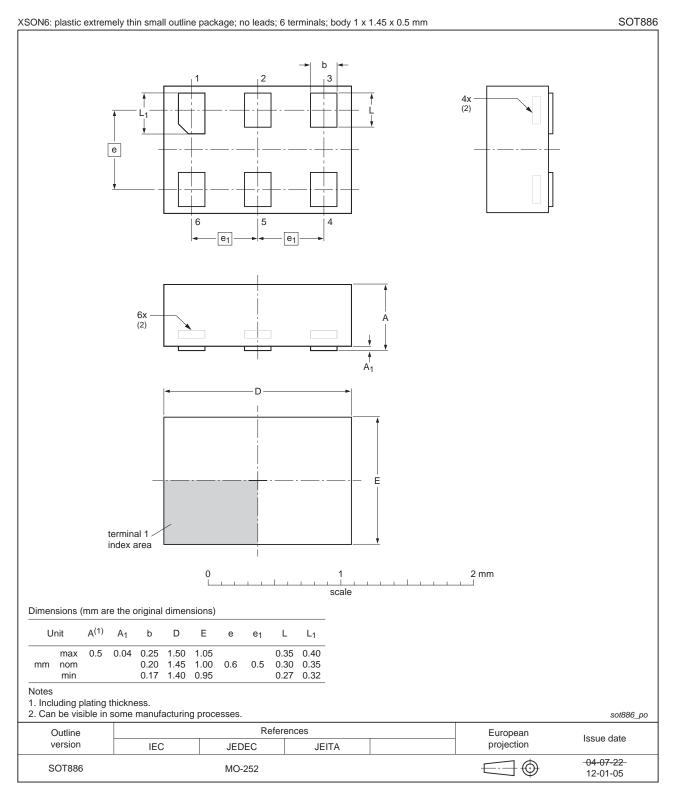


Fig 14. Package outline SOT363 (SC-88)

All information provided in this document is subject to legal disclaimers.

#### Low-power configurable gate with voltage-level translator



#### Fig 15. Package outline SOT886 (XSON6)

All information provided in this document is subject to legal disclaimers.

#### Low-power configurable gate with voltage-level translator

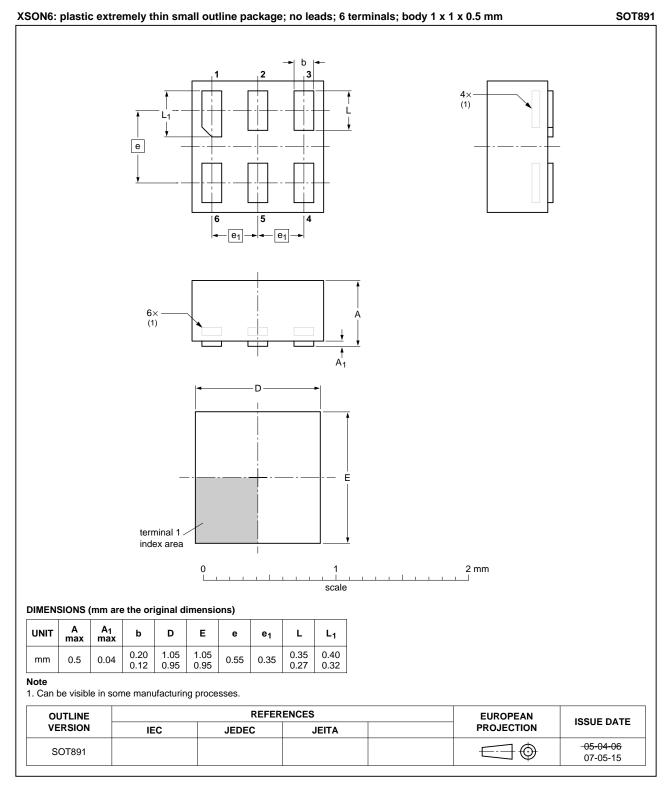
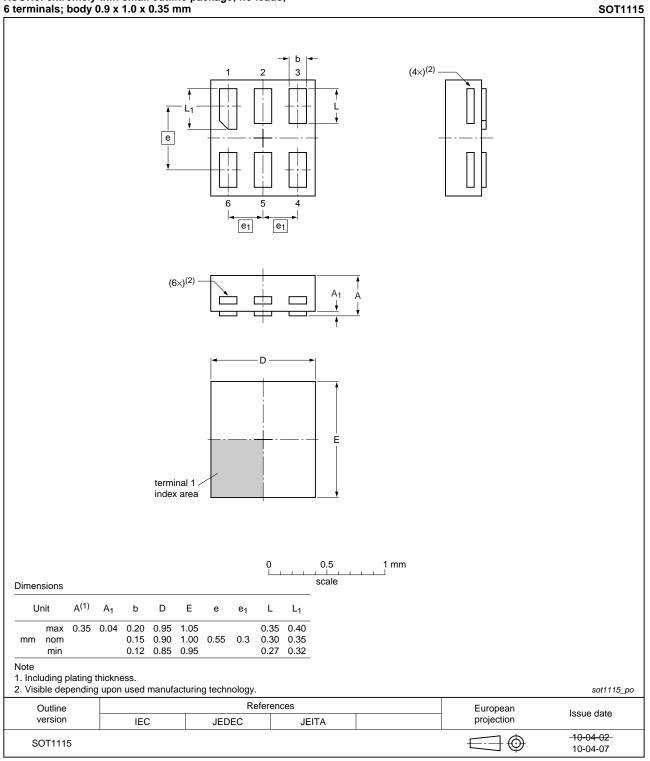


Fig 16. Package outline SOT891 (XSON6)

All information provided in this document is subject to legal disclaimers.

Low-power configurable gate with voltage-level translator

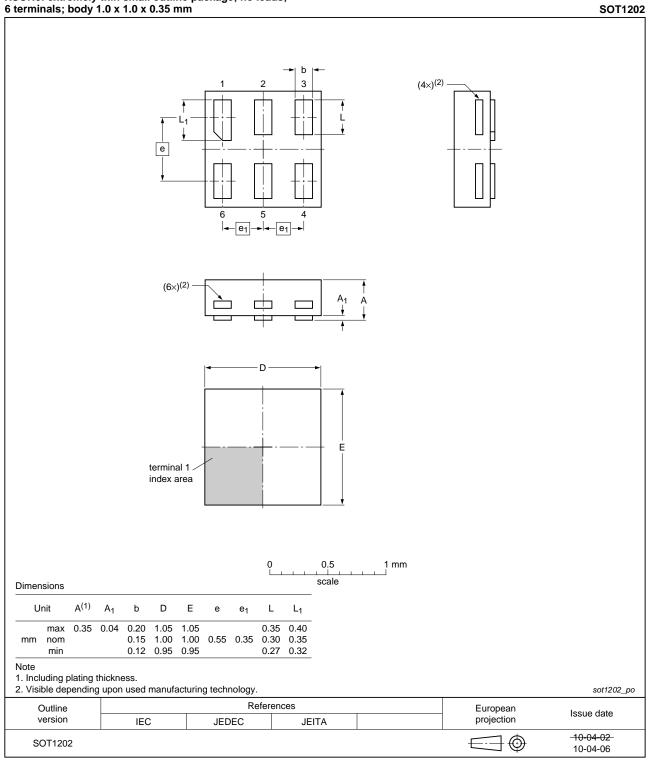


## XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 17. Package outline SOT1115 (XSON6)

All information provided in this document is subject to legal disclaimers.

Low-power configurable gate with voltage-level translator



## XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 18. Package outline SOT1202 (XSON6)

All information provided in this document is subject to legal disclaimers.

### Low-power configurable gate with voltage-level translator

## 14. Abbreviations

Table 12.	Table 12. Abbreviations			
Acronym	Description			
CDM	Charged Device Model			
CMOS	Complementary Metal Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			

## 15. Revision history

Table 13. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1T58 v.5	20120815	Product data sheet	-	74AUP1T58 v.4
Modifications:	<ul> <li>Package out</li> </ul>	tline drawing of SOT886 ( <mark>Figur</mark>	e 15) modified.	
74AUP1T58 v.4	20111128	Product data sheet	-	74AUP1T58 v.3
74AUP1T58 v.3	20101018	Product data sheet	-	74AUP1T58 v.2
74AUP1T58 v.2	20090929	Product data sheet	-	74AUP1T58 v.1
74AUP1T58 v.1	20080306	Product data sheet	-	-

### **16. Legal information**

#### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nexperia.com">http://www.nexperia.com</a>.

#### 16.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any

representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and

customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

**Right to make changes** — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof. Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia

products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

#### Nexperia

## 74AUP1T58

#### Low-power configurable gate with voltage-level translator

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Non-automotive qualified products** — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of

non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the

product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### 16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

### 17. Contact information

For more information, please visit: http://www.nexperia.com

For sales office addresses, please send an email to: salesaddresses@nexperia.com

### Nexperia

## 74AUP1T58

Low-power configurable gate with voltage-level translator

### **18. Contents**

1	General description 1
2	Features and benefits 1
3	Ordering information 2
4	Marking 2
5	Functional diagram 2
6	Pinning information 3
6.1	Pinning
6.2	Pin description 3
7	Functional description 3
7.1	Logic configurations 4
8	Limiting values 5
9	Recommended operating conditions 5
10	Static characteristics 6
11	Dynamic characteristics 8
12	Waveforms 10
13	Package outline 12
14	Abbreviations 17
15	Revision history 17
16	Legal information
16.1	Data sheet status 18
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks 19
17	Contact information 19
18	Contents

## **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Nexperia:

 74AUP1T58GF,132
 74AUP1T58GM,115
 74AUP1T58GM,132
 74AUP1T58GW,125
 74AUP1T58GN,132

 74AUP1T58GS,132
 74AUP1T58GS,132
 74AUP1T58GS,132
 74AUP1T58GS,132
 74AUP1T58GS,132